Seven indicators variations for multiple PV array configurations under partial shading and faulty PV conditions

Mahmoud Dhimish¹, Violeta Holmes¹, Bruce Mehrdadi¹, Mark Dales¹, Benjamin Chong², Li Zhang²

¹ School of Computing and Engineering, University of Huddersfield, United Kingdom
² School of Electronic and Electrical Engineering, University of Leeds, United Kingdom

Abstract

The goal of this paper is to model, compare and analyze the performance of multiple photovoltaic (PV) array configurations under various partial shading and faulty PV conditions. For this purpose, a multiple PV array configurations including series (S), parallel (P), series-parallel (SP), total-cross-tied (TCT) and bridge-linked (BL) are carried out under several partial shading conditions such as, increase or decrease in the partial shading on a row of PV modules and increase or decrease in the partial shading on a column of PV modules. Additionally, in order to test the performance of each PV configuration under faulty PV conditions, from 1 to 6 Faulty PV modules have been disconnected in each PV array configuration. Several indicators such as short circuit current (I_{sc}), current at maximum power point (I_{mpp}), open circuit voltage (V_{oc}), voltage at maximum power point (V_{mpp}), series resistance (R_s), fill factor (FF) and thermal voltage (V_t) have been used to compare the obtained results from each partial shading and PV faulty condition applied to the PV system. MATLAB/Simulink software is used to perform the simulation and the analysis for each examined PV array configuration.

Keywords: Multiple PV array configurations, Partial shading, Fault detection, MATLAB/Simulink

1. Introduction

Growing interest in renewable energy resources has caused the photovoltaic (PV) power market to expand rapidly. The power produced by grid-connected photovoltaic (GCPV) plants depends on various conditions such as PV module’s temperature and irradiance level. Shading by the surroundings directly effects both the cell temperature and irradiance level incident on the GCPV systems [1]. There are multiple reasons for the shading affects GCPV systems. K. Lappalainen & S. Valkealahti [2] discussed the output power variations of different PV array configurations during irradiance transition caused by moving cloud. The results shows that the average rate of change in the output power during irradiance transitions is around 3%, where the maximum rate of change is approximate to 75%. Furthermore, an accurate approach method to simulate the characteristics output of a PV systems under either partial shading or mismatch conditions is proposed by J. Bai et al [3]. The method is using the analysis of the current-voltage (I-V) and power-voltage (P-V) curves for various PV systems.

A highly detailed PV array model is developed by M. Vincenzo et al [4], the PV model was developed under non-uniform irradiance conditions using PSpice. The model assumed that the PV cells temperature are homogenous for each PV module which makes the simulation and modelling of the PV system less complex. The output results shows a good agreement between the simulation model vs. outdoor experimental results. The losses associated to shading effect can be reduced by using several approaches such as the maximum power point tracking (MPPT) techniques that allow the extension of the global maximum power point. R. Yeung et al [5] proposed a global MPPT algorithm which is based on extracting the power-voltage characteristics of the PV string through varying the input power impedance.
PV array configurations which is considered in this paper is one of solutions that can significantly reduce mismatch and shading losses in GCPV plants. It is based on the PV array interconnections of PV modules which are series (S), parallel (P), series-parallel (SP), total-cross-tied (TCT) and bridge-linked (BL) and many other configurations. Several attempts were proposed by researchers to study and analyze the effect of shading on different PV array configuration in order to reduce mismatch losses and providing the maximum output power generation. These attempts can be illustrated by the following:

1. **Comparison of various PV array configurations:**
   F. Belhachat & C. Larbes [6] detailed a brief comparison between five different PV array configurations (S, P, SP, TCT and BL configurations). The analysis is based on MATLAB/Simulink software. The results prove that TCT configuration achieved the optimum output power performance under most shading conditions. Moreover, [7] shows a mathematical analysis of TCT PV array configuration under partial shading conditions and its comparison with other PV array configurations such as BL and honey-comb (HC) configurations. Y. Wang & P. Hsu [8] found again that in most cases TCT configuration has a superior performance over the other PV array configurations such as S, P and SP. Some other publications are based on a comprehensive review on PV array configuration under partial shading conditions such as [9 & 10].

2. **New proposed PV array configuration:**
   S. Pareek & R. dahiya [11] proposed a new method that allows the distribution of shading effect evenly in each PV row thereby enhance the PV array output power. The PV characteristics curves for the proposed method is much smoother than other PV array configurations such as TCT. Furthermore, B. Rani et al [12] suggested a new method for increasing the power generation from PV array configuration. In the proposed approach, the physical location of the PV modules are connected using TCT configuration, but all PV arrays are arranged based on “Su Do Ku” puzzle pattern. The performance of the system is investigated for different shading patterns and the results show that positioning the modules of the array according to “Su Do Ku” puzzle pattern yields improved performance under partially shaded conditions. However, this method faces a drawbacks due to ineffective dispersion of shade and significant increase in wiring requirements, these disadvantages of the “Su Do Ku” method have been enhanced using a new technique which is proposed by S. Potnure et al [13].

3. **Power electronics techniques for enhancing PV power generation:**
   B. Chong & L. Zhang [14] proposed a new controller design for integrated PV-converter modules under partial shading conditions. The control results showing rapid and stable responses are superior to that obtained by bypass diode structure which is conventionally controlled using perturbation-and-observation method. Furthermore, a new GCPV based on cascaded H-Bridge quasi-z source inverter is presented by [15], the technique is used to verify the multilevel PV interface with AC inverters to enhance the power generation of GCPV systems. E. Koutroulis & F. Blaabjerg [16] proposed a new procedure for tracking the global maximum power point of PV arrays operating under partial shading conditions using D-flip/flop and analog/digital converter strategy. Additionally, a brief comprehensive maximum power point extraction using genetic algorithm is shown in [17].

4. **PV fault detection algorithms:**
   There are various methods used to detect faults in GCPV plants. Some of these methods use statistical analysis techniques such as t-test [18 & 19] and standard deviation limits [20].
Furthermore, machine learning techniques have been also applied in PV systems for fault detection purposes. ANN network was used by [21] for detection multiple faults in a PV system such as faulty PV modules and faulty bypass diodes. S. Silvestre et al [22] proposed a new procedure for fault detection in PV systems which is based on the analysis of the voltage and current ratios for the entire GCPV plant.

In this work, we present a detailed modelling, comparison and data analysis for multiple PV array configurations including the series (S), parallel (P), series-parallel (SP), total-cross-tied (TCT) and bridge-linked (BL) configurations. In order to compare the performance for each PV array configuration, various partial shading and faulty PV conditions have been tested. Several indicators such as short circuit current ($I_{sc}$), current at maximum power point ($I_{mpp}$), open circuit voltage ($V_{oc}$), voltage at maximum power point ($V_{mpp}$), series resistance ($R_s$), fill factor (FF) and thermal voltage ($V_{th}$) have been used to compare the obtained by the tested partial shading and faulty conditions.

Fig. 1 shows the overall examined PV array configurations, tested case scenarios and all indicators used to compare the performance between each PV array configuration. As can be noticed, the partial shading conditions applied in this paper is not static, which means that the partial shading conditions are either increasing or decreasing among all PV modules. Additionally, in order to test the performance of each PV array configuration under faulty PV conditions, from 1 to 6 Faulty PV modules have been disconnected in order to compare between each PV indicator variations.

From the literature, there is a few data analysis on the indicators variations among partial shading and faulty PV conditions applied to multiple PV array configurations, therefore, the main contribution of this article is the comparison and data analysis of multiple PV array configurations using seven different indicators. The examined indicators has not been fully covered in previously published articles such as [6-10]. Additionally, this research does not only examine several partial shading conditions affecting PV systems but also the modelling and the analysis of several faulty PV conditions (In-active PV modules) affecting various PV array configurations.

This paper is organized as follows: Section 2 presents the modelling and simulation for one PV module using MATLAB/Simulink software. Section 3 describes the calculation of the diagnostic indicators, while section 4 illustrates the simulation, modelling and data analysis of the examined PV array configurations. Finally, section 5 and section 6 describes the discussion and the conclusion respectively.
2. **Modelling and simulation of one PV module**

In this work, MATLAB/Simulink software is used to model, simulate and analyze the performance of the examined PV modules. Fig. 3(a) shows the equivalent circuit of a PV module. The voltage and the current characteristics of the PV module can be obtained using the single diode model [23] as explained in (1).

\[
I = I_{ph} - I_o \left( e^{\frac{V+IR_s}{N_sV_t}} - 1 \right) \left( \frac{V+IR_s}{R_{sh}} \right)
\]  

where \( I_{ph} \) is the photo-generated current at STC, \( I_o \) is the dark saturation current at STC, \( R_s \) is the module series resistance, \( R_{sh} \) is the panel parallel resistance, \( N_s \) is the number of series cells in the PV module and \( V_t \) is the thermal voltage and it can be calculated using (2).

\[
V_t = \frac{A k T}{q}
\]

where \( A \) the diode ideality factor, \( k \) is Boltzmann’s constant, \( T \) is the module temperature in kelvin and \( q \) is the charge of the electron.

The five parameters model are determined by solving the transcendental equation (1) using Newton-Raphson algorithm [24] based only on the datasheet of the available parameters shown in Table I. The power produced by PV module in watts can be easily calculated along with the current (I) and voltage (V) that is generated by equation (1), therefore, \( P_{theoretical} = IV \).

Fig 3(b) shows the PV module simulated at standard test conditions (STC):

- Irradiance 1000 W/m\(^2\), spectrum AM 1.5 G
- PV module temperature 25 °C

Using the MATLAB/Simulink software, it is possible to simulate the output voltage, current and the power of the PV module as shown in Fig. 3(c). As an example of simulation, Fig 2(a) and Fig2(b) show respectively the I-V and P-V curves of one PV module of 60 solar cells obtained with Simulink using the model described in Fig. 3(c). In this paper, the solar cell parameters used in the simulation are shown in Table1.

![Fig. 2. Simulation Results of MALTBAL/Simulink model. (a) Photovoltaic I-V Curve, (b) Photovoltaic P-V Curve](image-url)
Fig. 3. Photovoltaic Modelling Using MATLAB/Simulink. (a) Equivalent Circuit of a Solar Module, (b) Simulating PV Module under STC, (c) Simulating the Output Voltage, Current and Power of the PV Module

Table 1

<table>
<thead>
<tr>
<th>Solar panel electrical characteristics</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>Peak power</td>
<td>220 W</td>
</tr>
<tr>
<td>Voltage at maximum power point ( (V_{mp}) )</td>
<td>28.7 V</td>
</tr>
<tr>
<td>Current at maximum power point ( (I_{mp}) )</td>
<td>7.67 A</td>
</tr>
<tr>
<td>Open circuit voltage ( (V_{oc}) )</td>
<td>36.74 V</td>
</tr>
<tr>
<td>Short circuit current ( (I_{sc}) )</td>
<td>8.24 A</td>
</tr>
<tr>
<td>Number of cells connected in series</td>
<td>60</td>
</tr>
<tr>
<td>Number of cells connected in parallel</td>
<td>1</td>
</tr>
<tr>
<td>Series resistance ( (R_s) )</td>
<td>0.48484 Ω</td>
</tr>
<tr>
<td>Parallel resistance ( (R_{sh}) )</td>
<td>258.75 Ω</td>
</tr>
<tr>
<td>Dark saturation current ( (I_o) )</td>
<td>( 2.8 \times 10^{10} ) A</td>
</tr>
<tr>
<td>Ideal diode factor ( (A) )</td>
<td>0.9117</td>
</tr>
<tr>
<td>Boltzmann’s constant ( (k) )</td>
<td>( 1.3806 \times 10^{-23} ) J.K(^{-1})</td>
</tr>
</tbody>
</table>
3. Calculation of the diagnostic indicators

In order to compare the behavior of various PV array configurations. Firstly, it is required to identify the main indicators needed to investigate the change of the PV array configurations behavior. In this paper, a comparison between \( V_{mpp} \), \( V_{oc} \), \( I_{mpp} \), \( I_{sc} \) and \( P_{mpp} \) have been estimated for various PV array configurations. Additionally, new diagnostic indicators have been used and briefly explained in this section.

3.1 Equivalent thermal voltage (\( V_t \))

In previous work [25 & 27] an estimation of the thermal voltage of a PV model under partial shading conditions has been expressed by (3).

\[
V_t = \frac{(2V_{mpp} - V_{oc})(I_{sc} - I_{mp})}{I_{mp} - (I_{sc} - I_{mp}) \ln \left( \frac{I_{sc} - I_{mp}}{I_{sc}} \right)}
\]  

where \( V_{mp} \) is voltage at maximum power point, \( I_{mp} \) presents the current at the maximum power point, \( V_{oc} \) is the open circuit voltage and \( I_{sc} \) is the short circuit current estimated by the I-V or P-V curve of the PV module.

A second commonly used method to estimate the thermal voltage is to evaluate the change of the diode ideality factor \( A \) of the PV module [26]. This method can be calculated using (4).

\[
V_t = \frac{N_s A k T}{q}
\]

where \( N_s \) is the number of solar cells connected in series, \( k \) is the Boltzmann constant, \( T \) is the junction temperature in kelvin and \( q \) is equal to the charge of an electron.

In this paper, the first method was used to estimate the thermal voltage due to its simplicity and it does not require the estimation of the ideality factor for the PV modules [18]. The estimation of the ideality factor is usually cannot be calculated using the maximum power point tracking units provided in the PV systems. However, the first method does contain all parameters which are normally available to the user of the grid-connected PV (GCPV) plants.

The estimation of \( V_t \) for the PV module used in this paper under various irradiance levels (100~1000 W/m²) are shown in Fig. 4. The PV module temperature for all measurements is at STC 25 °C and the solar cell parameters used in the simulation are shown in Table 1.
3.2 Fill factor (FF)

The fill factor (FF) is a generic diagnostic indicator which is sensitive to power losses due to shading and faulty conditions occurring in PV systems [27]. FF is sufficiently robust to the irradiance change and the temperature levels. FF can be calculated using (5).

\[ FF = \frac{I_{mp} V_{mp}}{I_{sc} V_{oc}} \]  

The fill factor is a good indicator since it depends on the voltage and current changes in the PV modules. Fig. 5(a) shows the I-V curve of the PV module used in this work. Also it shows the location of the parameters used in the calculation of the FF indicator.

At STC, the PV module used in this work can be evaluated as shown in (6).

\[ FF = \frac{I_{mp} V_{mp}}{I_{sc} V_{oc}} = \frac{7.67 \times 28.7}{8.18 \times 36.74} = 73.25\% \]  

Fig. 5(b) shows the variations of the FF under various irradiance levels (100~1000 W/m²).
3.3 PV series resistance ($R_s$)

**Method 1:**

One commonly used method to estimate $R_s$ is to evaluate the derivative of the voltage with respect to the current at the $V_{oc}$. The final expression to approximate the series resistance is described by (7).

$$R_{s,e} = - \left. \frac{dV}{dl} \right| V \approx V_{oc} = - \frac{V_2-V_1}{I_2-I_1} \left. V \approx V_{oc} \right.$$ (7)

where $V_2$, $V_1$, $I_2$ and $I_1$ are the voltage and the current points estimated near to $V_{oc}$.

The value of the series resistance estimated by the derivative may vary with the irradiance conditions [28]. D. Sara et al [29] proposed a method to translate the value of the estimated $R_s$ to STC in order to mitigate the effect of the irradiance ($G$) and PV module temperature ($T$). The expression is illustrated by (8).

$$R_s = R_{s,e} + \frac{V_{te}}{I_{sc}} \left( \frac{G}{G_{STC}} \times \frac{T_{STC}}{T} - 1 \right)$$ (8)

where $G_{STC}$ is equal to 1000 W/m$^2$ and $T_{STC}$ is equal to 25 °C.

As can be noticed, the estimation of the series resistance requires the voltage and the current measurements of at least two point of the I-V curve close to the $V_{oc}$. The method also requires the value of the irradiance and the PV modules temperature to perform the estimation of the series resistance value.

**Method 2:**

Another method of estimating the series resistance of a PV module is to evaluate the derivative of the voltage with respect to the current at the short circuit and maximum power point, such point is characterized by a current lower, but closer to $I_{mpp}$ and it is denominated as $Q$. This method was proposed by [21] and used in [27 and 28] for the estimation of $R_s$. There are two options to calculate $Q$ (9 & 10).

$$Q_1 = I_{sc,e} - (0.75 \times I_{mpp})$$ (9)

$$Q_2 = I_{sc,e} - (0.60 \times I_{mpp})$$ (10)

where the value of $I_{sc,e}$ is the estimated short circuit current and can be evaluated using (11).

$$I_{sc,e} = \frac{I_{sc}}{K_1}$$ (11)

where $K_1$ is the ratio between $I_{mpp}$ and $I_{sc}$ and it is assumed as constant value of 0.92 as described by [21].

The final expression of estimating the value of the series resistance is expressed by (12).

$$R_s = - \left. \frac{dV}{dl} \right| I \approx Q = - \frac{V_2-V_1}{I_2-I_1} \left. I \approx Q \right.$$ (12)

The evaluation of the series resistance requires at least two points of the I-V curve for the PV module.

Furthermore, it is required to measure:

1. Current at maximum power point ($I_{mpp}$)
2. Short circuit current ($I_{sc}$)
Fig. 6 shows the value of the series resistance estimated using method 1 and method 2. The estimated values of the $R_s$ are compared with the measured $R_s$. Therefore, the difference between the measured values with the estimated values can be expressed by (13).

$$\text{Difference} = \text{Estimated } R_s - \text{Measured } R_s \quad (13)$$

Table 2 shows the comparison between the estimated $R_s$ and measured $R_s$ using method 1: at $V_{oc}$, and method 2: at Q1 and Q2. The minimum average difference is equal to 1.71% obtained for method 1. Therefore, in this paper, method 1 is used for the estimation of $R_s$.
4. Simulation, modelling and data analysis of multiple PV array configurations

The aim of this section is to present the multiple PV array configurations used in this study. In order to test the multiple PV array configurations, 24 PV modules were used. Each PV module consists of 60 PV modules connected in series and protected by bypass diodes. The PV modules temperature was fixed at the standard test condition (STC) 25 °C.

4.1 Types of examined PV array configurations

Five common PV array configurations were used in order to examine the main indicators which are mostly changeable during the normal operation mode, partial shading and faulty PV conditions. The examined PV array configurations are listed as the following:

1. Series (S) configuration
2. Parallel (P) configuration
3. Series-Parallel (SP) configuration
4. Total-Cross-Tied (TCT) configuration
5. Bridge-Linked (BL) configuration

MATLAB/Simulink software is used to create the listed PV array configurations. Appendix A contains all MATLAB/Simulink software models which are used to configure the grid-connected PV (GCPV) systems. Furthermore, during the simulation all indicators: $V_{mp}$, $V_{oc}$, $I_{mp}$, $I_{sc}$, $P_{mp}$, $R_s$, FF and $V_{oc}$ were saved in a spreadsheet to evaluate the performance of each PV array configuration separately.

4.2 PV array configurations under STC

This section presents the variations of all required indicators at standard test conditions applied to the PV array configurations. Table 3 shows the value of all indicators for the different PV array configurations. The main outcomes from the obtained results can be expressed by the following:

1. Series configuration: the dominant indicator is the value of the $V_{oc}$, $V_{mp}$ and the value of the thermal voltage.
2. Parallel configuration: $I_{sc}$, $I_{mpp}$ and the thermal voltage which has the least value across all PV configurations.
3. SP, TCT and BL configurations have a common similarity across all indicators.
4. At STC, the FF for all PV configurations is approximately equal to 73.2%.

From Table 4 it is possible to evaluate the value of the series resistance across one PV module in the GCPV systems according to the mathematical expressions listed below in Table 3.

<table>
<thead>
<tr>
<th>PV array configuration</th>
<th>Mathematical expression for estimating the value of $R_s$ for one PV module in the PV array configuration</th>
</tr>
</thead>
<tbody>
<tr>
<td>S</td>
<td>$\frac{R_s \text{ (obtained from the } I-V \text{ curve)}}{24 \text{ (total PV module in the PV array configuration)}}$ (14)</td>
</tr>
<tr>
<td>P</td>
<td>$R_s \text{ (obtained from the } I-V \text{ curve)} \times \frac{24 \text{ (total PV module in the PV array configuration)}}{6 \text{ (number of PV modules in one PV row &quot;PV String&quot;)}}$ (15)</td>
</tr>
<tr>
<td>SP, TCT and BL</td>
<td>$R_s \text{ (obtained from the } I-V \text{ curve)} \times \frac{4 \text{ (number of PV columns)}}{6 \text{ (number of PV modules in one PV row &quot;PV String&quot;)}}$ (16)</td>
</tr>
</tbody>
</table>
Table 5 shows that the estimation of the series resistance for a single PV module using the mathematical expressions listed in Table 3 at STC. There is a slightly difference between the real measured $R_s$ values at STC with the calculated $R_s$ using (14-16). The percentage of the average difference between the measured $R_s$ and the calculated $R_s$ is equal to 2.2%.

### Table 4

<table>
<thead>
<tr>
<th>PV configuration</th>
<th>$I_{sc}$ (A)</th>
<th>$V_{oc}$ (V)</th>
<th>$I_{mpp}$ (A)</th>
<th>$V_{mpp}$ (V)</th>
<th>$P_{mpp}$ (W)</th>
<th>$R_s$ (Ω)</th>
<th>$V_{te}$ (V)</th>
<th>FF (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>S</td>
<td>8.177</td>
<td>881.2</td>
<td>7.538</td>
<td>700.3</td>
<td>5279</td>
<td>12.18175</td>
<td>36.2059</td>
<td>73.2608</td>
</tr>
<tr>
<td>P</td>
<td>196.2</td>
<td>36.74</td>
<td>181.4</td>
<td>29.1</td>
<td>5279</td>
<td>0.020116</td>
<td>1.44597</td>
<td>73.2305</td>
</tr>
<tr>
<td>SP</td>
<td>32.71</td>
<td>220.3</td>
<td>30.26</td>
<td>174.4</td>
<td>5279</td>
<td>0.757576</td>
<td>8.59957</td>
<td>73.2353</td>
</tr>
<tr>
<td>TCT</td>
<td>32.71</td>
<td>220.3</td>
<td>30.33</td>
<td>174</td>
<td>5278</td>
<td>0.757576</td>
<td>8.31149</td>
<td>73.2363</td>
</tr>
<tr>
<td>BL</td>
<td>32.71</td>
<td>220.3</td>
<td>30.33</td>
<td>174</td>
<td>5278</td>
<td>0.757576</td>
<td>8.31149</td>
<td>73.2363</td>
</tr>
</tbody>
</table>

### Table 5

<table>
<thead>
<tr>
<th>PV configuration</th>
<th>$R_s$ (Ω)</th>
<th>Calculated $R_s$ for one PV module (Ω)</th>
<th>Measured $R_s$ for one PV module at STC (Ω)</th>
<th>Difference in the estimation of $R_s$ (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>S</td>
<td>12.18175</td>
<td>0.507573</td>
<td>0.48484</td>
<td>2.273299</td>
</tr>
<tr>
<td>P</td>
<td>0.020116</td>
<td>0.482772</td>
<td>0.48484</td>
<td>-0.20675</td>
</tr>
<tr>
<td>SP</td>
<td>0.757576</td>
<td>0.505051</td>
<td>0.48484</td>
<td>2.021051</td>
</tr>
<tr>
<td>TCT</td>
<td>0.757576</td>
<td>0.505051</td>
<td>0.48484</td>
<td>2.021051</td>
</tr>
<tr>
<td>BL</td>
<td>0.757576</td>
<td>0.505051</td>
<td>0.48484</td>
<td>2.021051</td>
</tr>
</tbody>
</table>

### 4.3 Partial shading conditions applied to the PV array configurations

In order to evaluate the behavior of each PV configuration under non-uniform irradiance conditions and to choose the most optimal configuration that provides that highest performance and identifying the main indicators which are changing significantly in each PV configuration, two different shading scenarios and two faulty PV conditions were tested for each PV configuration under a fixed temperature 25 °C.

#### 4.3.1 Scenario 1: row level

In this part, the focus will be on the performance of the PV configurations which are affected by a uniformly and non-uniform shading patterns on a row level (row of PV modules). Fig. 7 shows both patterns used to evaluate the row shading conditions effects on the PV modules.

As can be noticed from Fig. 7, two different partial shading conditions was performed. The first partial shading pattern is applied on a row of PV modules at irradiance level equal to 500 W/m². However, the second shading pattern consists of various irradiance levels (200, 400, 600 and 800 W/m²) applied to four PV modules.

Fig. 8(a) shows the maximum output power obtained in each PV array configuration under shading pattern 1. The P configuration shows the maximum output power comparing to all other examined PV array configurations. The configurations S, SP, TCT and BL provide the same maximum power in each case.
Fig. 8(b) proves that P configuration has the maximum output power among all other PV array configurations under shading pattern 2. TCT and BL comes second best choice whereas the series configuration has the lowest performance.

In each shading pattern, the series resistance ($R_s$) was estimated using method 1 which has been discussed previously in section 3.3. Table 6 shows the estimated $R_s$ for each PV array configuration for shading pattern 1. $R_s$ estimated for the S configuration is increased by approximate to 1.13 Ω. Additionally, the estimated series resistance for SP, TCT and BL configurations is increased by approximate to 0.07 Ω. There is a very small amount of change in the series resistance obtained for P configuration, the reduction is only equal to 0.002 Ω.
Table 7 shows the estimated \( R_s \) for partial shading pattern 2. The S configuration has an increase by 1.8 \( \Omega \) in the \( R_s \). Moreover, the parallel configuration has the lowest rate of change in the \( R_s \), which is approximate equal to 0.002. SP, TCT and BL configurations has an increase of 0.07 \( \Omega \) in the \( R_s \) among all testes cases in the row level partial shading conditions.

The FF indicator was also calculated for each examined partial shading patterns. Fig. 9(a) and Fig 9(b) illustrates the FF variations among the tested GCPV systems for shading pattern 1 and shading pattern 2 respectively. The P configuration shows that the FF has a value close to 73% among all tested case scenarios. However, a reduction in the FF was obtained across all other PV array configurations.

The Thermal voltage \( V_{te} \) across each PV array configuration during the tested partial shading pattern1 and pattern 2 are shown in Fig. 9(c) and Fig. 9(d) respectively. The threshold values of the \( V_{te} \) is taken from Table 4. It is evident that the \( V_{te} \) for P configuration is approximate equal to 1.44V which is exactly the same as the P configuration \( V_{te} \) threshold. S, SP, TCT and BL configurations show that the value of \( V_{te} \) is lower than the value of \( V_{te} \) threshold in low partial shading conditions if: reduction in irradiance < 6000 W/m². However, in most partial shading conditions examined in this section, the obtained value of the \( V_{te} \) is greater than the value of \( V_{te} \) threshold if: reduction in the irradiance \( \geq \) 6000 W/m².

From this section, the obtained results could be illustrated as the following:

- \( R_s \) could be a good indicator to predict/estimate partial shading conditions for S, SP, TCT and BL configurations. However, \( R_s \) cannot be used with P configuration since it does not change significantly during the increase/decrease of the partial shading conditions applied PV system.
- FF has a significant drop in its value while increasing the partial shading in the S, SP, TCT and BL configurations. This is not a proper indicator to be used with P configuration since it does not change among all tested partial shading conditions.
- When the reduction in the irradiance is greater or equal to 6000 W/m², the value of the \( V_{te} \) in most partial shading conditions is greater than the value of \( V_{te} \) threshold for S, SP, TCT and BL configurations. However, P configurations shows that the value of the \( V_{te} \) is almost equal to the value of \( V_{te} \) threshold.
Fig. 9. FF and $V_{oc}$ Variations for Scenario 1: Row Level. (a) Fill Factor Variations for Pattern 1, (b) Fill Factor Variations for Pattern 2, (c) $V_{oc}$ Variations for Pattern 1, (d) $V_{oc}$ Variations for Pattern 2.
### 4.3.2 Scenario 2: Column Level

This section is created to check the variations of the $R_s$, $V_{oc}$, FF indicators when a partial shading conditions occurred in the PV array configuration on a column level (column of PV modules).

Fig. 10 shows two different partial shading patterns examined. The first partial shading pattern is applied on a column of PV modules at irradiance level equal to 500 W/m². However, the second shading pattern consists of various irradiance levels (100, 200, 500, 600, 800 and 900 W/m²) applied to six PV modules.

Fig. 11(a) shows the maximum output power obtained in each PV array configuration under shading pattern 1. P, SP, TCT and BL configurations shows approximately the same maximum output power. Furthermore, S configuration provides the minimum output power during all examined case scenarios used in shading pattern 1. On the other hand, the maximum output power obtained from shading pattern 2 is illustrated in Fig. 11(b). The maximum output power could be evaluated at the P configuration. However, S configuration remains the worst configuration.

In each shading pattern (pattern 1 and 2), the series resistance ($R_s$) was estimated. Table 8 shows the estimated $R_s$ for each PV array configuration for shading pattern 1. As can be noticed, $R_s$ estimated for the S configuration is increasing by approximate to 1.68 Ω. This result can be calculated using the difference between case1 and case2, where the values of $R_s$ are taken from the measured data explained in table 2:

$$\text{Estimated } R_s = \text{Number of PV modules (at partial shading condition)} \times R_s \text{ (at partial shading condition)}$$

**Case1:**

$$\text{Estimated } R_s = \left( \frac{6 \text{ at } 500 \text{ W/m}^2}{1000 \text{ W/m}^2} \times 0.789787 \right) + \left( \frac{18 \text{ at } 1000 \text{ W/m}^2}{1000 \text{ W/m}^2} \times 0.48484 \right) = 13.47 \Omega$$

**Case2:**

$$\text{Estimated } R_s = \left( \frac{12 \text{ at } 500 \text{ W/m}^2}{1000 \text{ W/m}^2} \times 0.789787 \right) + \left( \frac{12 \text{ at } 1000 \text{ W/m}^2}{1000 \text{ W/m}^2} \times 0.48484 \right) = 15.30 \Omega$$

$$\text{Difference} = \text{Case2} - \text{Case1} = 15.3 - 13.47 = 1.83 \Omega \approx 1.68 \Omega \text{ Obtained by the I – V curve}$$

---

**Fig. 10. Partial Shading Patterns for Scenario 2: Column Level**
Additionally, the estimated series resistance for SP, TCT and BL configurations is increasing by approximate to 0.12 Ω. However, the parallel configuration remains at nearly constant series resistance between 0.02 – 0.03 Ω.

For the second shading pattern (non-uniform irradiance) the estimated $R_s$ for SP, TCT and BL configurations is increasing by 0.3 Ω. The parallel configuration remains at the same $R_s$ which is between 0.02 – 0.03 Ω. Similarly, the estimated series resistance for S configuration is increasing by 4.4 Ω while increasing the applied partial shading on the PV array configuration, this can be seen in Table 9 and described by the following mathematical calculations, where the values of $R_s$ are taken from the measured data explained in table 2:

$$
\text{Measured } R_s = \text{Number of PV modules (at partial shading condition)} \times R_s (\text{at partial shading condition})
$$

**Case 1: Measured $R_s$**

$$
\begin{align*}
\text{Case 1: } R_s &= \left( 1\left(\text{at } 100 \frac{W}{m^2}\right) \times 3.241 \right) + \left( 1\left(\text{at } 200 \frac{W}{m^2}\right) \times 1.668 \right) + \left( 1\left(\text{at } 500 \frac{W}{m^2}\right) \times 0.789787 \right) \\
&\quad + \left( 1\left(\text{at } 600 \frac{W}{m^2}\right) \times 0.6988 \right) + \left( 1\left(\text{at } 800 \frac{W}{m^2}\right) \times 0.5677 \right) + \left( 1\left(\text{at } 900 \frac{W}{m^2}\right) \times 0.5378 \right) \\
&\quad + \left( 1\left(\text{at } 1000 \frac{W}{m^2}\right) \times 0.48484 \right) = 16.25 \Omega
\end{align*}
$$

**Case 2: Measured $R_s$**

$$
\begin{align*}
\text{Case 2: } R_s &= \left( 2\left(\text{at } 100 \frac{W}{m^2}\right) \times 3.241 \right) + \left( 2\left(\text{at } 200 \frac{W}{m^2}\right) \times 1.668 \right) + \left( 2\left(\text{at } 500 \frac{W}{m^2}\right) \times 0.789787 \right) \\
&\quad + \left( 2\left(\text{at } 600 \frac{W}{m^2}\right) \times 0.6988 \right) + \left( 2\left(\text{at } 800 \frac{W}{m^2}\right) \times 0.5677 \right) + \left( 2\left(\text{at } 900 \frac{W}{m^2}\right) \times 0.5378 \right) \\
&\quad + \left( 2\left(\text{at } 1000 \frac{W}{m^2}\right) \times 0.48484 \right) = 20.865 \Omega
\end{align*}
$$

**Difference** = Case 2 – Case 1 = 20.865 – 16.25 = 4.6 Ω ≈ 4.4 Ω Obtained by the I – V curve

**Table 8**

Estimated $R_s$ for the Multiple Array Configurations, Scenario 2: Column Level, Pattern 1

<table>
<thead>
<tr>
<th>Case #</th>
<th>S (Ω)</th>
<th>P (Ω)</th>
<th>SP (Ω)</th>
<th>TCT (Ω)</th>
<th>BL (Ω)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Case 1</td>
<td>13.8754</td>
<td>0.022921</td>
<td>0.818197</td>
<td>0.818197</td>
<td>0.818197</td>
</tr>
<tr>
<td>Case 2</td>
<td>15.55936</td>
<td>0.025198</td>
<td>0.898957</td>
<td>0.898957</td>
<td>0.898957</td>
</tr>
<tr>
<td>Case 3</td>
<td>17.26519</td>
<td>0.028329</td>
<td>1.012146</td>
<td>1.012146</td>
<td>1.012146</td>
</tr>
<tr>
<td>Case 4</td>
<td>18.93581</td>
<td>0.033034</td>
<td>1.176471</td>
<td>1.176471</td>
<td>1.176471</td>
</tr>
</tbody>
</table>

**Fig. 11.** Partial Shading Patterns for Scenario 2: Column Level. (a) Output Power for Pattern 1, (b) Output power for Pattern 2
Fig. 12(a) and Fig. 12(b) illustrates the FF variations among the tested PV array configuration systems for shading pattern 1 and shading pattern 2 respectively. Shading pattern 1 shows that P, SP, TCT and BL configurations have a value of FF approximate to 74% among all tested cases. However, a reduction in the FF was only obtained across the S configuration. Shading pattern 2 (non-uniform shading) shows a different results comparing to shading pattern 1 (uniform shading), these results could be illustrated as the following:

- The estimated FF for the P configuration under non-uniform and uniform shading patterns are exactly equal.
- There is a huge reduction in the FF for S, SP, TCT and BL configurations in the non-uniform shading pattern conditions.
- Fig. 12(a) shows that the value of the FF for the S configuration at case 4 is equal to 74% because in this particular shading case, the percentage of shading among all PV modules are equal.

The Thermal voltage \( V_{te} \) across each PV array configuration during the tested partial shading pattern1 and pattern 2 are shown in Fig. 12(c) and Fig. 9(d) respectively. The threshold values of the \( V_{te} \) is taken from Table 4. It is evident that the \( V_{te} \) for P configuration is approximate equal to 1.44V which is exactly the same as the P configuration \( V_{te} \) threshold. The estimated values of the \( V_{te} \) for SP, TCT and BL configurations are exactly the same as the \( V_{te} \) threshold during shading pattern 1. However, the estimated \( V_{te} \) for S configuration is greater than the value of the \( V_{te} \) threshold if:

\[
\text{Reduction in irradiance} \geq 6000 \text{W/m}^2.
\]

Fig. 12(d) shows that the estimated \( V_{te} \) is exactly the same as the \( V_{te} \) threshold for shading pattern 2. SP, TCT and BL configurations proves that when the reduction in the irradiance is greater than 2900 W/m², the estimated value of \( V_{te} \) is always greater than \( V_{te} \) threshold. Moreover, S configuration shows that the value of the \( V_{te} \) is greater than \( V_{te} \) threshold if: Reduction in irradiance \( \geq 6000 \text{W/m}^2 \).

Table 9

<table>
<thead>
<tr>
<th>Case #</th>
<th>S</th>
<th>P</th>
<th>SP</th>
<th>TCT</th>
<th>BL</th>
</tr>
</thead>
<tbody>
<tr>
<td>Case 1</td>
<td>16.85772</td>
<td>0.022861</td>
<td>0.83675</td>
<td>0.819403</td>
<td>0.823045</td>
</tr>
<tr>
<td>Case 2</td>
<td>21.33106</td>
<td>0.025054</td>
<td>0.961538</td>
<td>0.918274</td>
<td>0.929195</td>
</tr>
<tr>
<td>Case 3</td>
<td>25.75992</td>
<td>0.02809</td>
<td>1.186662</td>
<td>1.106195</td>
<td>1.119821</td>
</tr>
<tr>
<td>Case 4</td>
<td>30.08424</td>
<td>0.032468</td>
<td>1.845018</td>
<td>1.845359</td>
<td>1.845359</td>
</tr>
</tbody>
</table>

In conclusion, this section shows some results on the performance of the examined PV array configurations under uniform and non-uniform partial shading patterns. The main findings could be illustrated as the following:

- Under uniform shading patterns which effects on a column of PV modules, the output power for P, SP, TCT and BL configurations are exactly the same. Furthermore, the S configuration shows the least output power among all PV array configurations.
- Under non-uniform shading patterns which effects on a column of PV modules, the optimum output power was estimated for the parallel configuration.
- The series resistance \( R_s \) is a good indicator for detecting/predicting partial shading conditions for S, SP, TCT and BL configurations since the value of the \( R_s \) change significantly while increasing the partial shading conditions applied to the PV configurations.
- The Fill factor (FF) indicator could be used with SP, TCT and BL configurations only under non-uniform irradiance conditions. Furthermore, there is a large drop in the value of FF for the S configuration under uniform and non-uniform irradiance levels.
- The value of the \( V_{te} \) could be used as a proper indicator for detecting partial shading conditions for S, SP, TCT and BL configuration under non-uniform partial shading conditions affecting the GCPV plants.
Fig. 12. FF and $V_{inc}$ Variations for Scenario 2: Column Level. (a) Fill Factor Variations for Pattern 1, (b) Fill Factor Variations for Pattern 2, (c) $V_{inc}$ Variations for Pattern 1, (d) $V_{inc}$ Variations for Pattern 2
4.3.3 Scenario 3: faulty PV modules

This section is created to check the variations of the $R_s$, $V_{oc}$, FF indicators when a faulty PV modules have been raised in the PV array configurations.

Two faulty scenarios were carried out to estimate the output performance for each PV array configuration under faulty PV modules. Fig. 13 illustrates both cases which can be described by the following:

1. Row level: six different scenarios were tested to estimate the faulty PV modules which are disconnected (short circuit the PV module) from a row of the PV array configuration.

2. Column level: four different scenarios were tested to estimate the faulty PV modules which are disconnected from the entire column of the PV array configuration.

The PV modules irradiance and temperature level are at standard test conditions: 1000W/m$^2$ and 25 °C respectively.

Fig. 14(a) and Fig 14(b) shows that the configurations S and P provides the highest maximum output power among all PV array configurations. The second maximum output power is achieved by the SP configuration. However, the minimum output power is estimated for the TCT configuration among all faulty PV case scenarios.

The estimated series resistance $R_s$ for the row-level PV faulty conditions are illustrated in Table 10. The S configuration shows that $R_s$ is decreasing by 0.49 Ω while disconnecting one PV module. This result is approximate equal to the measured value of $R_s$ among one PV module (0.48484 Ω) under STC as shown previously in Table 5.

The estimated $R_s$ for the column-level PV faulty conditions are illustrated in Table 11. As can be noticed that the value of $R_s$ in the S and SP configurations is decreased while increasing the number of faulty PV modules. The estimated $R_s$ for TCT and BL is increasing for the first three PV faulty conditions. However, the estimated $R_s$ is equal to 0.63 Ω when disconnecting an entire PV column from the PV array configuration is equal to 1.007 Ω for SP, TCT and BL configurations, this value could be calculated using (16) as the following:

$$\text{Estimated } R_s \text{ for one PV module} = \frac{R_s (\text{obtained from the } I-V \text{ Curve}) \times 3}{6 (\text{number of PV modules in one PV row } \text{"PV String"})}$$

$$0.48484 = \frac{R_s (\text{obtained from the } I-V \text{ Curve}) \times 3 \text{ (Since one PV string is completely disconnected})}{6}$$

$$R_s (\text{obtained from the } I-V \text{ Curve}) = 0.97 \Omega \approx 1.007 \Omega$$

The estimated series resistance $R_s$ for the column-level PV faulty conditions are illustrated in Table 11. As can be noticed that the value of $R_s$ in the S and SP configurations is decreased while increasing the number of faulty PV modules. The estimated $R_s$ for TCT and BL is increasing for the first three PV faulty conditions. However, the estimated $R_s$ is equal to 0.63 Ω when disconnecting an entire PV column from the SP, TCT and BL array configurations. This result could be estimated using (16) as the following:

$$\text{Estimated } R_s \text{ for one PV module} = \frac{R_s (\text{obtained from the } I-V \text{ Curve}) \times 4}{5 (\text{number of PV modules in one PV row } \text{"PV String"})}$$

$$0.48484 = \frac{R_s (\text{obtained from the } I-V \text{ Curve}) \times 4 \text{ (Since one PV string is completely disconnected})}{5}$$

$$R_s (\text{obtained from the } I-V \text{ Curve}) = 0.61 \Omega \approx 0.63 \Omega$$
Fig. 15(a) and Fig. 15(b) illustrates the FF variations among the tested PV array configurations using faulty conditions: row-level and column level respectively. Row-level PV faulty conditions show that S, P and TCT configurations have a value of FF approximate to 73.2% among all tested scenarios. However, a reduction in the FF was only obtained across the SP and BL configurations. The column-level PV faulty conditions shows that the FF for the S and P configuration remains at 73.2%. Furthermore, there is a huge reduction in the estimated FF for both TCT and BL configurations. The only configuration which has an increase in the estimated values of the FF was obtained for the SP configuration.

As shown in Fig. 15(a) at case 6 (Faulty PV string) the estimated value of the FF across all PV array configurations is equal to 73.2%. Similar results obtained for case 4 (faulty column) illustrated in Fig 15(b).
The Thermal voltage $V_{te}$ estimated for each PV array configuration under faulty PV modules conditions (row-level and column-level) are shown in Fig. 15(c) and Fig. 9(d) respectively. From Fig. 15(c), it is evident that $V_{te}$ for P configuration is equal to 1.36V among all PV faulty conditions; this result is approximately equal to P configuration $V_{te}$ threshold: 1.44V. The estimated value of the $V_{te}$ for S, SP, TCT and BL configurations is decreased while increasing the number of faulty PV modules in the PV array configuration due to the decrease in the $V_{mp}$. Despite the decrease of $V_{oc}$, the value of $V_{mp}$ is multiplied by a factor of 2, therefore, $V_{te}$ is also decreasing. This results can be expressed by the following:

$$V_{te} \downarrow = \frac{(2V_{mp} \downarrow - V_{oc} \downarrow)(I_{sc} \downarrow - I_{mp} \downarrow)}{I_{mp} \downarrow - (I_{sc} \downarrow - I_{mp} \downarrow) \ln(I_{sc} \downarrow - I_{mp} \downarrow)}$$

Different results obtained at case6 in Fig. 15(c), where a faulty PV string occurred in each PV configuration. The value of $V_{te}$ for the SP, TCT and BL is increased because the value of the $I_{sc}$ and $I_{mp}$ is decreased:

$$V_{te} \uparrow = \frac{(2V_{mp} \downarrow - V_{oc} \downarrow)(I_{sc} \downarrow - I_{mp} \downarrow)}{I_{mp} \downarrow - (I_{sc} \downarrow - I_{mp} \downarrow) \ln(I_{sc} \downarrow - I_{mp} \downarrow)}$$

Similar results obtained for the estimated $V_{te}$ in the column-level faulty PV conditions as shown in Fig 15(d). The main findings of this section can be listed as the following:

- When the number of faulty PV modules in increasing the estimated $R_s$ is decreasing in S, SP TCT and BL configurations.
- The FF for the S and P configurations among all faulty PV conditions remains at 73.2%.
- The estimated value of $V_{te}$ for S, SP, TCT and BL configurations is decreased while increasing the number of faulty PV modules. However, in case of the faulty PV string occurred in the PV system, the value of the $V_{te}$ is increased only in SP, TCT and BL configurations.
- P configuration has approximately constant levels of FF and $V_{te}$ among all tested PV faulty conditions.

### Table 10
Estimated $R_s$ for the Multiple Array Configurations, Scenario 3: PV Faulty Conditions, Row Level

<table>
<thead>
<tr>
<th>Case #</th>
<th>Estimated $R_s$ (Ω)</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>S</td>
</tr>
<tr>
<td>Case 1</td>
<td>11.57273</td>
</tr>
<tr>
<td>Case 2</td>
<td>11.08033</td>
</tr>
<tr>
<td>Case 3</td>
<td>10.58574</td>
</tr>
<tr>
<td>Case 4</td>
<td>10.08065</td>
</tr>
<tr>
<td>Case 5</td>
<td>9.581603</td>
</tr>
<tr>
<td>Case 6</td>
<td>9.077156</td>
</tr>
</tbody>
</table>

### Table 11
Estimated $R_s$ for the Multiple Array Configurations, Scenario 3: PV Faulty Conditions, Column Level

<table>
<thead>
<tr>
<th>Case #</th>
<th>Estimated $R_s$ (Ω)</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>S</td>
</tr>
<tr>
<td>Case 1</td>
<td>11.57273</td>
</tr>
<tr>
<td>Case 2</td>
<td>11.08033</td>
</tr>
<tr>
<td>Case 3</td>
<td>10.58574</td>
</tr>
<tr>
<td>Case 4</td>
<td>10.08065</td>
</tr>
</tbody>
</table>
Fig. 15. FF and $V_{oc}$ Variations for Scenario 3: Faulty PV Conditions. (a) Fill Factor Variations for Row Level PV Faulty Conditions, (b) Fill Factor Variations for Column Level PV Faulty Conditions, (c) $V_{oc}$ Variations for Row Level PV Faulty Conditions, (d) $V_{oc}$ Variations for Column Level PV Faulty Conditions.
5. Discussion

In this paper a brief modelling, simulation and data analysis of various partial shading and PV faulty modules conditions have been discussed. Multiple diagnostic indicators have been used to compare the performance of each PV array configuration such as short circuit current ($I_{sc}$), current at maximum power point ($I_{mpp}$), open circuit voltage ($V_{oc}$), voltage at maximum power point ($V_{mpp}$), series resistance ($R_s$), fill factor (FF) and thermal voltage ($V_{te}$). Few of these indictors have been demonstrated by F. Belhachat [6].

However, the partial shading conditions applied in this paper is not static as shown in [6, 7, 9 and 13], which means that the partial shading conditions are either increasing or decreasing among all PV modules. Additionally, in order to test the performance of each PV array configuration under faulty PV conditions, from 1 to 6 Faulty PV modules have been disconnected in order to compare between each PV indicator variations, this scenario has been demonstrated in section 4.3.3. Currently, there are few research articles which combines between faulty PV conditions with multiple PV array configurations. Therefore, this section is one of the major contribution for this paper.

The obtained results of this research can be divided into four main categories:

1. **PV array configurations under standard test condition (STC):**
   - The S, P, SP, TCT and BL configurations provide the same maximum output power.
   - FF for all PV array configurations is approximately equal to 73.2%.
   - New mathematical expressions have been derived for estimating the value of the series resistance $R_s$ across one PV module in all tested PV array configurations.

2. **PV array configurations under uniform partial shading conditions:**
   - P configuration provides the maximum output power when one to five rows or/and one to four columns are completely shaded.
   - S, SP, TCT and BL configurations have an increase of the $R_s$ while increase the uniform shading across the PV modules. While P configuration series resistance remains at the same value which is approximate to 0.02 $\Omega$.
   - FF for the S, SP, TCT and BL configurations have a significant drop in its value while increasing the uniform partials shading condition applied to a row of PV modules. However, the P configuration FF remains at a threshold of 74%.
   - The value of $V_{te}$ is not a proper indicator for predicting/estimating the change in the partial shading conditions for S, SP, TCT and BL since it does not change among all tested uniform partial shading conditions.

3. **PV array configurations under non-uniform partial shading conditions:**
   - P configuration provides the maximum output power when one to five rows and/or one to four columns are completely shaded. Furthermore, TCT configuration provided the second optimum output power among all other PV array configurations.
   - S, SP, TCT and BL configurations have an increase of the $R_s$ while increase the non-uniform shading across the PV modules. While P configuration series resistance remains at the same value which is approximate to 0.02 $\Omega$.
   - SP, TCT and BL configurations proves that when the reduction in the irradiance is greater than 2900 W/m² the estimated value of $V_{te}$ is always greater than $V_{te}$ threshold. Moreover, S configuration shows that the value of the $V_{te}$ is greater than $V_{te}$ threshold if: Reduction in irradiance $\geq 6000$ W/m².
4. **PV array configurations under faulty PV conditions:**

- P configuration provides the maximum output power when one to five PV modules are faulty in a row of PV modules and when one to four PV modules are disconnected from a column of PV modules in the PV array configuration.

- The estimation of the $R_s$ of a single PV module in the PV array configurations can be calculated using the following mathematical expression:

  \[
  \begin{align*}
  & \text{S configuration} \quad R_s \left( \text{obtained from the } I-V \text{ curve} \right) \\
  & \quad \quad \div 24 \left( \text{total PV module in the PV array configuration} \right) \\
  & \text{P configuration} \quad R_s \left( \text{obtained from the } I-V \text{ curve} \right) \times 24 \left( \text{total PV module in the PV array configuration} \right) \\
  & \text{SP, TCT and BL configurations} \quad R_s \left( \text{obtained from the } I-V \text{ curve} \right) \times 4 \left( \text{number of PV columns} \right) \div 6 \left( \text{number of PV modules in one PV row ‘PV String’} \right)
  \end{align*}
  \]

- The estimated value of $V_{oc}$ for S, SP, TCT and BL configurations is decreased while increasing the number of faulty PV modules. However, in case of faulty PV string occurred in the PV system, the value of the $V_{oc}$ is increased only in SP, TCT and BL configurations.

- The FF for the S and P configurations among all faulty PV conditions remains at 73.2%. However, for all other PV configurations the estimated value of the FF is either increasing or decreasing.

From the obtained results, it is evident that the variations of $I_{sc}$, $I_{mpp}$, $V_{oc}$, and $V_{mpp}$ are not shown. This is because the value of these indicators have been widely discussed by many research articles such as [6, 7, 9 and 13]. However, all listed references does not include the increase or decrease of shading patterns among all PV configurations, additionally, there are few of discussions about faulty PV modules in multiple PV array configurations.

Table 12, 13 and 14 illustrates the variations for all indicators used in this article among all examined partial shading and faulty PV conditions in the S, P, SP, TCT and BL PV array configurations. Three different symbols are used to show whether the value of the indicator has an "↓" decrease, "↑" increase, "-" no change in its value and "↓↑" decrease or increase in the value of the indicator. A brief discussion of the indicators $R_s$, FF and $V_{oc}$ are is available in section 4.

The S, SP, TCT and BL configurations have always a reduction in the value of $V_{oc}$ while increasing the uniform, non-uniform shading conditions and increasing the number of faulty PV modules. The P configuration has a reduction in the $V_{oc}$ among all shading patterns, however, $V_{oc}$ remains constant while increasing or decreasing the number of faulty PV modules.

In most tested conditions, the value of the $I_{sc}$ has no change for the S, SP, TCT and BL configurations. The P configuration proves that the value of $I_{sc}$ is always decreasing while increasing the uniform, non-uniform shading conditions and increasing the number of faulty PV modules.

The voltage at maximum power point ($V_{mpp}$) is not a proper indicator for estimating/predicting partial shading conditions or and faulty PV modules in the S, SP, TCT and BL configuration because in each tested condition the value of $V_{mpp}$ is either increased or decreased. However, this comment is not applicable for the P configuration because the value of the $V_{mpp}$ is always decreasing while increasing the partial shading conditions applied to the PV plant.
The last indicator, $I_{mpp}$ is a proper indicator to estimate/predict partial shading conditions in all examined PV array configurations since the value of the indicator is decreasing while increasing shading conditions. The value of $I_{mpp}$ does not change while increasing/decreasing number of faulty PV modules in S, SP, TCT and BL configurations. However, it does change significantly for the P configuration.

### Table 12
Change in the Estimated Indicators on Each PV Array Configuration

<table>
<thead>
<tr>
<th>Scenario</th>
<th>PV array configurations</th>
<th>S</th>
<th>P</th>
</tr>
</thead>
<tbody>
<tr>
<td>Increasing uniform shading on PV row</td>
<td>$I_{sc}$ $I_{mpp}$ $V_{oc}$ $V_{mpp}$ $R_s$ $FF$ $V_{te}$</td>
<td>- $↓$ $↓$ $↓↑$ $↑$ $↓$ $↑$</td>
<td>$↓$ $↓$ $↓$ $↓$ $¬$ $¬$ $¬$</td>
</tr>
<tr>
<td>Increasing non-uniform shading on PV row</td>
<td>$I_{sc}$ $I_{mpp}$ $V_{oc}$ $V_{mpp}$ $R_s$ $FF$ $V_{te}$</td>
<td>$¬$ $¬$ $¬$ $¬$ $¬$ $¬$ $¬$</td>
<td>$¬$ $¬$ $¬$ $¬$ $¬$ $¬$ $¬$</td>
</tr>
<tr>
<td>Increasing uniform shading on PV column</td>
<td>$I_{sc}$ $I_{mpp}$ $V_{oc}$ $V_{mpp}$ $R_s$ $FF$ $V_{te}$</td>
<td>$¬$ $¬$ $¬$ $¬$ $¬$ $¬$ $¬$</td>
<td>$¬$ $¬$ $¬$ $¬$ $¬$ $¬$ $¬$</td>
</tr>
<tr>
<td>Increasing non-uniform shading on PV column</td>
<td>$I_{sc}$ $I_{mpp}$ $V_{oc}$ $V_{mpp}$ $R_s$ $FF$ $V_{te}$</td>
<td>$¬$ $¬$ $¬$ $¬$ $¬$ $¬$ $¬$</td>
<td>$¬$ $¬$ $¬$ $¬$ $¬$ $¬$ $¬$</td>
</tr>
<tr>
<td>Increasing faulty PV modules in PV row</td>
<td>$I_{sc}$ $I_{mpp}$ $V_{oc}$ $V_{mpp}$ $R_s$ $FF$ $V_{te}$</td>
<td>$¬$ $¬$ $¬$ $¬$ $¬$ $¬$ $¬$</td>
<td>$¬$ $¬$ $¬$ $¬$ $¬$ $¬$ $¬$</td>
</tr>
<tr>
<td>Increasing faulty PV modules in PV column</td>
<td>$I_{sc}$ $I_{mpp}$ $V_{oc}$ $V_{mpp}$ $R_s$ $FF$ $V_{te}$</td>
<td>$¬$ $¬$ $¬$ $¬$ $¬$ $¬$ $¬$</td>
<td>$¬$ $¬$ $¬$ $¬$ $¬$ $¬$ $¬$</td>
</tr>
</tbody>
</table>

### Table 13
Change in the Estimated Indicators on Each PV Array Configuration

<table>
<thead>
<tr>
<th>Scenario</th>
<th>PV array configurations</th>
<th>SP</th>
<th>TCT</th>
</tr>
</thead>
<tbody>
<tr>
<td>Increasing uniform shading on PV row</td>
<td>$I_{sc}$ $I_{mpp}$ $V_{oc}$ $V_{mpp}$ $R_s$ $FF$ $V_{te}$</td>
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<td>$¬$ $¬$ $¬$ $¬$ $¬$ $¬$ $¬$</td>
</tr>
</tbody>
</table>
6. **Conclusion**

In this paper, multiple PV array configurations including series (S), parallel (P), series-parallel (SP), total-cross-tied (TCT) and bridge-lined (BL) have been tested under various partial shading and faulty photovoltaic (PV) conditions. Several indicators such as short circuit current ($I_{sc}$), current at maximum power point ($I_{mpp}$), open circuit voltage ($V_{oc}$), voltage at maximum power point ($V_{mpp}$), series resistance ($R_s$), fill factor (FF) and thermal voltage ($V_{te}$) have been used to compare the obtained results from the partial shading and PV faulty conditions. MATLAB/Simulink software is used to perform the simulation and data analysis for each examined PV array configuration.

The variations for all indicators across all PV array configurations have been reported and compared briefly. Additionally, new mathematical expressions have been derived to estimate the value of the series resistance across a single PV module in each PV array configuration under standard test conditions (STC) and faulty PV modules.

Finally, this study gives a useful information on the main parameters that could be used for estimating/predicting partial shading conditions in all examined PV array configurations. Therefore, the results obtained from this study could be enhanced by creating a generic algorithm using machine learning techniques for detecting faulty PV modules in multiple PV array configurations or/and creating a reconfigurable PV array system to improve the power generation in grid-connected PV (GCPV) plants.

7. **Acknowledgment**

The authors would like to acknowledge the financial assistant to the University of Huddersfield, Engineering and Computing Department.
Appendix A. MATLAB/Simulink model for the examined PV array configurations.

Series (S) Configuration:

Parallel (P) Configuration:
Series-Parallel (SP) Configuration:

Total-Cross-Tied (TCT) Configuration:
Bridge-Linked (BL) Configuration:

References


